

Vishay Siliconix

Automotive Dual N-Channel 20 V (D-S) 175 °C MOSFET



Marking Code: 9H

PRODUCT SUMMARY				
V _{DS} (V)	20			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.280			
$R_{DS(on)}$ (Ω) at $V_{GS} = 2.5 \text{ V}$	0.360			
$R_{DS(on)}$ (Ω) at $V_{GS} = 1.8 \text{ V}$	0.450			
I _D (A)	0.8			
Configuration	Dual			
Package	SC-70			

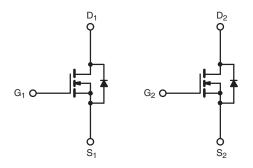
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V_{DS}	20	V	
Gate-source voltage		V_{GS}	± 8	V	
Continuous drain current ^a	T _C = 25 °C	I _D	0.8		
Continuous drain current "	T _C = 125 °C		0.8		
Continuous source current (diode conduction) a	I _S	0.8	Α		
Pulsed drain current ^b		I _{DM}	3		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	3.8		
Single pulse avalanche energy		E _{AS}	7.2	mJ	
Maximum power dissipation ^b	T _C = 25 °C	В	1.5	W	
Maximum power dissipation -	T _C = 125 °C	P_{D}	0.5	V V	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R_{thJA}	220	°C/W	
Junction-to-foot (drain)		R_{thJF}	100	C/VV	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static				l			
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \mu A$		20	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	0.45	0.6	1.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 20 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μΑ
		$V_{GS} = 0 V$	$V_{DS} = 20 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 4.5 \text{ V}$	$V_{DS} \ge 5 \text{ V}$	1.5	-	-	Α
		$V_{GS} = 4.5 \text{ V}$	I _D = 1.2 A	-	0.200	0.280	
		$V_{GS} = 4.5 \text{ V}$	I _D = 1.2 A, T _J = 125 °C	-	-	0.423	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}$	$I_D = 1.2 \text{ A}, T_J = 175^{\circ}\text{C}$	-	-	0.510	Ω
		$V_{GS} = 2.5 \text{ V}$	I _D = 1 A	-	0.261	0.360	
		V _{GS} = 1.8 V	I _D = 0.2 A	-	0.320	0.450	<u>ז</u>
Forward transconductance b	9 _{fs}	V _{DS} :	= 10 V, I _D = 0.5 A	-	2.6	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	49	75	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 10 \text{ V}, f = 1 \text{ MHz}$	-	22	32	pF
Reverse transfer capacitance	C _{rss}			-	8	12	
Total gate charge ^c	Q_g			-	0.76	1.15	
Gate-source charge ^c	Q_{gs}	$V_{GS} = 4.5 \text{ V}$	$V_{DS} = 10 \text{ V}, I_{D} = 1.2 \text{ A}$	-	0.13	1	nC
Gate-drain charge ^c	Q_{gd}			-	0.33	1	
Gate resistance ^d	R_g	f = 1 MHz		5.5	11.1	22.2	Ω
Turn-on delay time ^c	t _{d(on)}			-	3	5	
Rise time ^c	t _r	$V_{DD} = 10 \text{ V}, R_L = 20 \Omega$ $I_D \cong 0.5 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		-	21	31	no
Turn-off delay time ^c	t _{d(off)}			-	19	29	ns
Fall time ^c	t _f			-	17	25	
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	3	Α
Forward voltage	V_{SD}	$I_F = 0.5 \text{ A}, V_{GS} = 0$		_	0.8	1.2	V

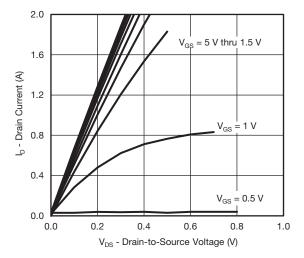
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

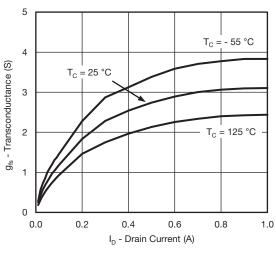
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



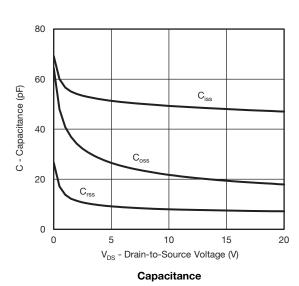
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

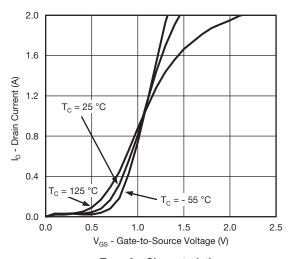


Output Characteristics

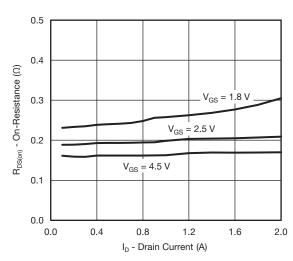


Transconductance

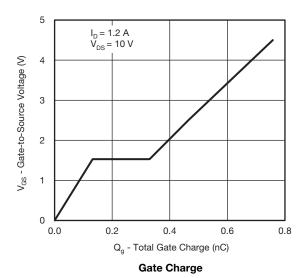




Transfer Characteristics

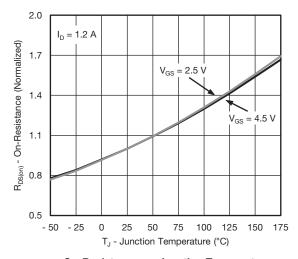


On-Resistance vs. Drain Current

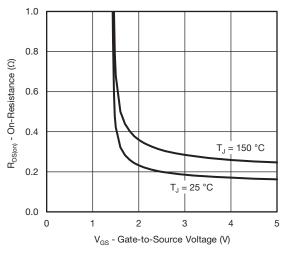




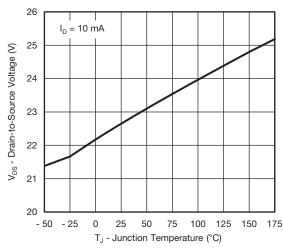
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



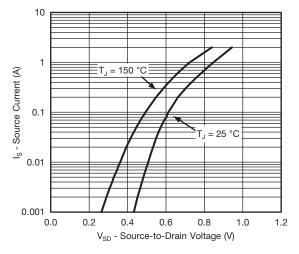
On-Resistance vs. Junction Temperature



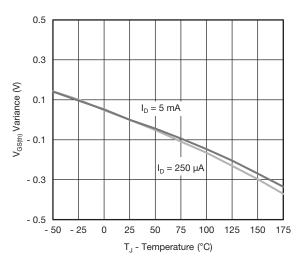
On-Resistance vs. Gate-to-Source Voltage



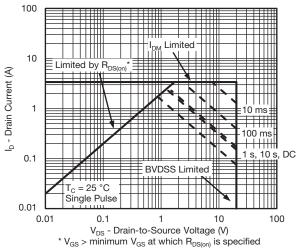
Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage



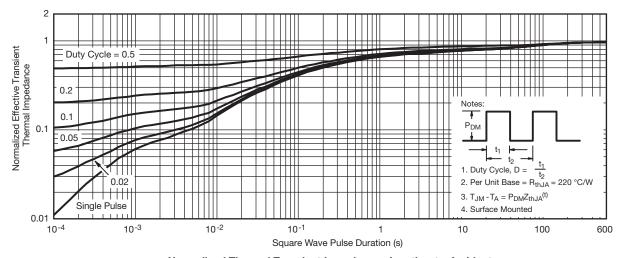
Threshold Voltage



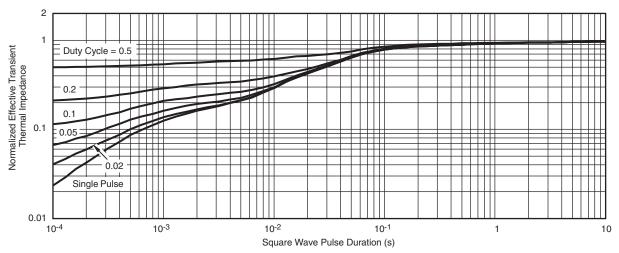
Safe Operating Area



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

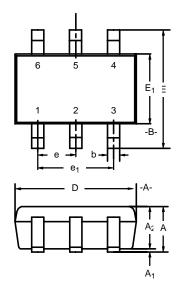
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

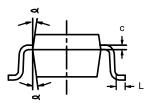
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67394.





SC-70: 6-LEADS



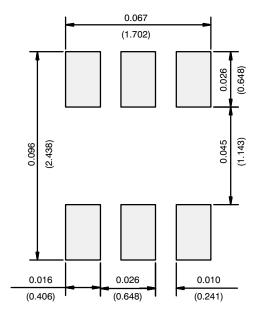


	MILLIMETERS			TERS INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A ₁	-	_	0.10	-	_	0.004
A ₂	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	-	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Ε	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65BSC			0.026BSC	;
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
کے	7°Nom				7°Nom	

DWG: 5550



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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Power MOSFETs

Application Note AN917

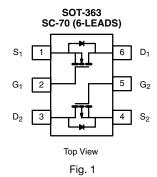
Dual-Channel LITTLE FOOT® 6-Pin SC-70 MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance 175 °C Rated Part

INTRODUCTION

The new dual 6-pin SC-70 package with a copper leadframe enables improved on-resistance values and enhanced thermal performance as compared to the existing 3-pin and 6-pin packages with Alloy 42 leadframes. These devices are intended for small to medium load applications where a miniaturized package is required. Devices in this package come in a range of on-resistance values, in n-channel and p-channel versions. This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for the dual-channel version.

PIN-OUT

Figure 1 shows the pin-out description and pin 1 identification for the dual-channel SC-70 device in the 6-pin configuration. Both n-and p-channel devices are available in this package – the drawing example below illustrates the p-channel device.



For package dimensions see outline drawing SC-70 (6-Leads) (www.vishay.com/doc?71154)

BASIC PAD PATTERNS

Revision: 15-Apr-13

See Application Note 826, Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs, (www.vishay.com/doc?72286) for the SC-70 6-pin basic pad layout and dimensions. This pad pattern is sufficient for the low-power applications for which this package is intended. Increasing the drain pad pattern (figure 2) yields a reduction in thermal resistance and is a preferred footprint.

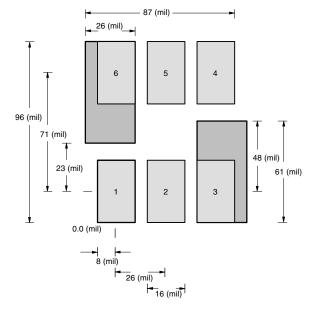


Fig. 2 SC-70 (6 leads) Dual

EVALUATION BOARD FOR THE DUAL-CHANNEL SC70-6

The 6-pin SC-70 evaluation board (EVB) shown in figure 3 measures 0.6 in. by 0.5 in. The copper pad traces are the same as described in the previous section, Basic Pad Patterns. The board allows for examination from the outer pins to the 6-pin DIP connections, permitting test sockets to be used in evaluation testing.

The thermal performance of the dual 6-pin SC-70 has been measured on the EVB, comparing both the copper and Alloy > 42 leadframes. This test was then repeated using the 1-inch² PCB with dual-side copper coating.

A helpful way of displaying the thermal performance of the 6-pin SC-70 dual copper leadframe is to compare it to the traditional Alloy 42 version.

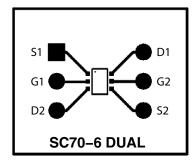
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Dual-Channel LITTLE FOOT® 6-Pin SC-70 MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance 175 °C Rated Part

Front of Board SC70-6



Back of Board SC70-6

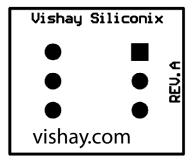


Fig. 3

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (the Package Performance)

Thermal performance for the dual SC-70 6-pin package is measured as junction-to-foot thermal resistance, in which the "foot" is the drain lead of the device as it connects with the body. The junction-to-foot thermal resistance for this device is typically 80 °C/W, with a maximum thermal resistance of approximately 100 °C/W. This data compares favorably with another compact, dual-channel package - the dual TSOP-6 - which features a typical thermal resistance of 75 °C/W and a maximum of 90 °C/W.

Power Dissipation for 175 °C Rated Part

The typical R θ JA for the dual-channel 6-pin SC-70 with a copper leadframe is 224 °C/W steady-state, compared to 413 °C/W for the Alloy 42 version. All figures are based on the 1-inch² FR4 test board. The following example shows how the thermal resistance impacts power dissipation for the dual 6-pin SC-70 package at varying ambient temperatures.

Alloy 42 Leadframe

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PLICATION

Д

ALLOY 42 LEADFRAME			
ROOM AMBIENT 25 °C	ELEVATED AMBIENT 60 °C		
$P_D = \frac{T_{J(max.)} - T_A}{R\theta_{JA}}$	$P_{D} = \frac{T_{J(max.)} - T_{A}}{R\theta_{JA}}$		
$P_{D} = \frac{175 ^{\circ}\text{C} - 25 ^{\circ}\text{C}}{413 ^{\circ}\text{C/W}}$	$P_{D} = \frac{175 ^{\circ}\text{C} - 60 ^{\circ}\text{C}}{413 ^{\circ}\text{C/W}}$		
$P_D = 363 \text{ mW}$	$P_D = 278 \text{ mW}$		

COOPER LEADFRAME				
ROOM AMBIENT 25 °C	ELEVATED AMBIENT 60 °C			
$P_{D} = \frac{T_{J(max.)} - T_{A}}{R\theta_{JA}}$	$P_{D} = \frac{T_{J(max.)} - T_{A}}{R\theta_{JA}}$			
$P_{D} = \frac{175 ^{\circ}\text{C} - 25 ^{\circ}\text{C}}{224 ^{\circ}\text{C/W}}$	$P_D = \frac{175 ^{\circ}\text{C} - 60 ^{\circ}\text{C}}{224 ^{\circ}\text{C/W}}$			
$P_D = 669 \text{ mW}$	$P_D = 513 \text{ mW}$			

Although they are intended for low-power applications, devices in the 6-pin SC-70 dual-channel configuration will handle power dissipation in excess of 0.5 W.

TESTING

To further aid the comparison of copper and Alloy 42 leadframes, Figures 4 and 5 illustrate the dual-channel 6-pin SC-70 thermal performance on two different board sizes and pad patterns. The measured steady-state values of $R\theta_{JA}$ for the dual 6-pin SC-70 with varying leadframes are as follows:

LITTLE FOOT 6-PIN SC-70				
	ALLOY 42	COPPER		
1) Minimum recommended pad pattern on the EVB board (see fig. 3).	518 °C/W	344 °C/W		
2) Industry standard 1-inch ² PCB with maximum copper both sides.	413 °C/W	224 °C/W		

The results indicate that designers can reduce thermal resistance (θ_{JA}) by 34 % simply by using the copper leadframe device as opposed to the Alloy 42 version. In this example, a 174 °C/W reduction was achieved without an increase in board area. If an increase in board size is feasible, a further 120 °C/W reduction can be obtained by utilizing a 1-inch². PCB area.

Revision: 15-Apr-13 2 Document Number: 75130



Vishay Siliconix

Dual-Channel LITTLE FOOT® 6-Pin SC-70 MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance 175 °C Rated Part

The dual copper leadframe versions have the following suffix:

Dual: Sx19xxEDH or Sx19xxEEH

Compl.: Sx15xxEDH or Sx15xxEEH

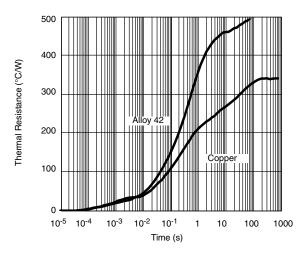


Fig. 4 Dual SC70-6 Thermal Performance on EVB

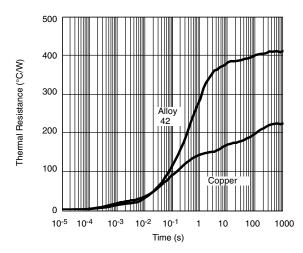


Fig. 5 Dual SC70-6 Comparison on 1-inch² PCB



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